MSD1819A-RT1

Preferred Device

General Purpose Amplifier Transistor

NPN Silicon Surface Mount

This NPN Silicon Epitaxial Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- High h_{FE}, 210–460
- Low V_{CE(sat)}, < 0.5 V
- Moisture Sensitivity Level 1
- ESD Protection: Human Body Model > 4000 V Machine Model > 400 V
- Pb–Free Package is Available

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current – Continuous	۱ _C	100	mAdc
Collector Current – Peak	I _{C(P)}	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 1)	PD	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

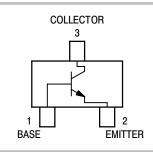
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



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SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



ZR = Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MSD1819A-RT1	SC-70/ SOT-323	3000/Tape & Reel
MSD1819A-RT1G	SC-70/ SOT-323 (Pb-Free)	3000/Tape & Reel

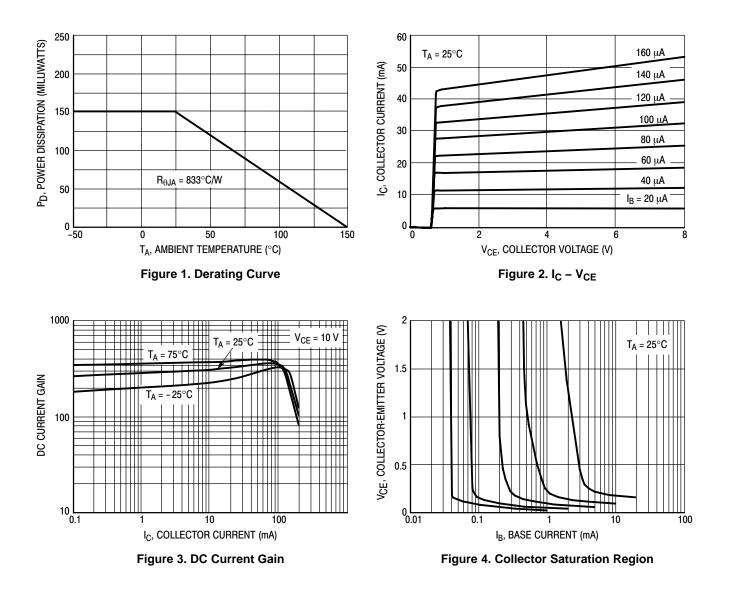
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ($I_C = 2.0 \text{ mAdc}, I_B = 0$)	V _{(BR)CEO}	50	-	Vdc
Collector-Base Breakdown Voltage ($I_C = 10 \ \mu Adc$, $I_E = 0$)	V _{(BR)CBO}	60	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10 \ \mu Adc$, $I_E = 0$)	V _{(BR)EBO}	7.0	-	Vdc
Collector-Base Cutoff Current ($V_{CB} = 20$ Vdc, $I_E = 0$)	I _{CBO}	-	0.1	μΑ
Collector-Emitter Cutoff Current (V_{CE} = 10 Vdc, I_B = 0)	I _{CEO}	-	0.1	μΑ
DC Current Gain (Note 2) (V_{CE} = 10 Vdc, I _C = 2.0 mAdc) (V_{CE} = 2.0 Vdc, I _C = 100 mAdc)	h _{FE1} h _{FE2}	210 90	340 -	_
Collector-Emitter Saturation Voltage (Note 2) ($I_C = 100$ mAdc, $I_B = 10$ mAdc)	V _{CE(sat)}	-	0.5	Vdc

2. Pulse Test: Pulse Width \leq 300 µs, D.C. \leq 2%.



MSD1819A-RT1

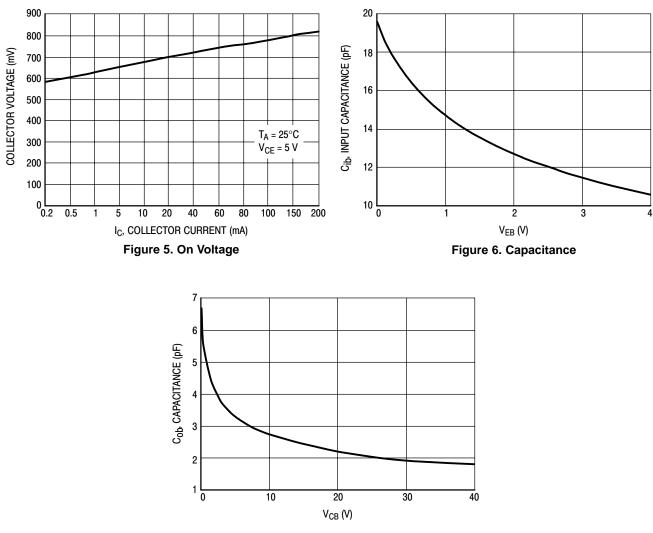
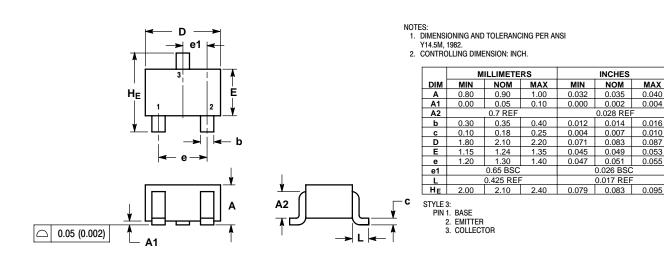


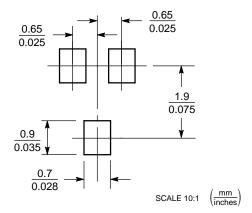
Figure 7. Capacitance

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE M



SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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